NSN 5961-01-388-5516

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-388-5516 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud and terminal Thready Qty Per Inch (tpi): 40 **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon alloy Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Power Rating Per Characteristic:** 7.5 watts small-signal input power, common-collector horsepower metric **Capacitance Rating In Picofarads:** 1.2 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 95105-992-6518 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 ribbon and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No